



HIGH-SPEED 4K x 8 FourPort™ STATIC RAM

IDT7054S/L

Features

- ♦ **High-speed access**
 - Commercial: 20/25/35ns (max.)
 - Industrial: 25ns (max.)
- ♦ **Low-power operation**
 - IDT7054S
 - Active: 750mW (typ.)
 - Standby: 7.5mW (typ.)
 - IDT7054L
 - Active: 750mW (typ.)
 - Standby: 1.5mW (typ.)
- ♦ **True FourPort memory cells which allow simultaneous access of the same memory locations**
- ♦ **Fully asynchronous operation from each of the four ports: P1, P2, P3, and P4**
- ♦ **TTL-compatible; single 5V (±10%) power supply**
- ♦ **Available in 128 pin Thin Quad Flatpack package**

- ♦ Industrial temperature range (–40°C to +85°C) is available for selected speeds
- ♦ Green parts available, see ordering information

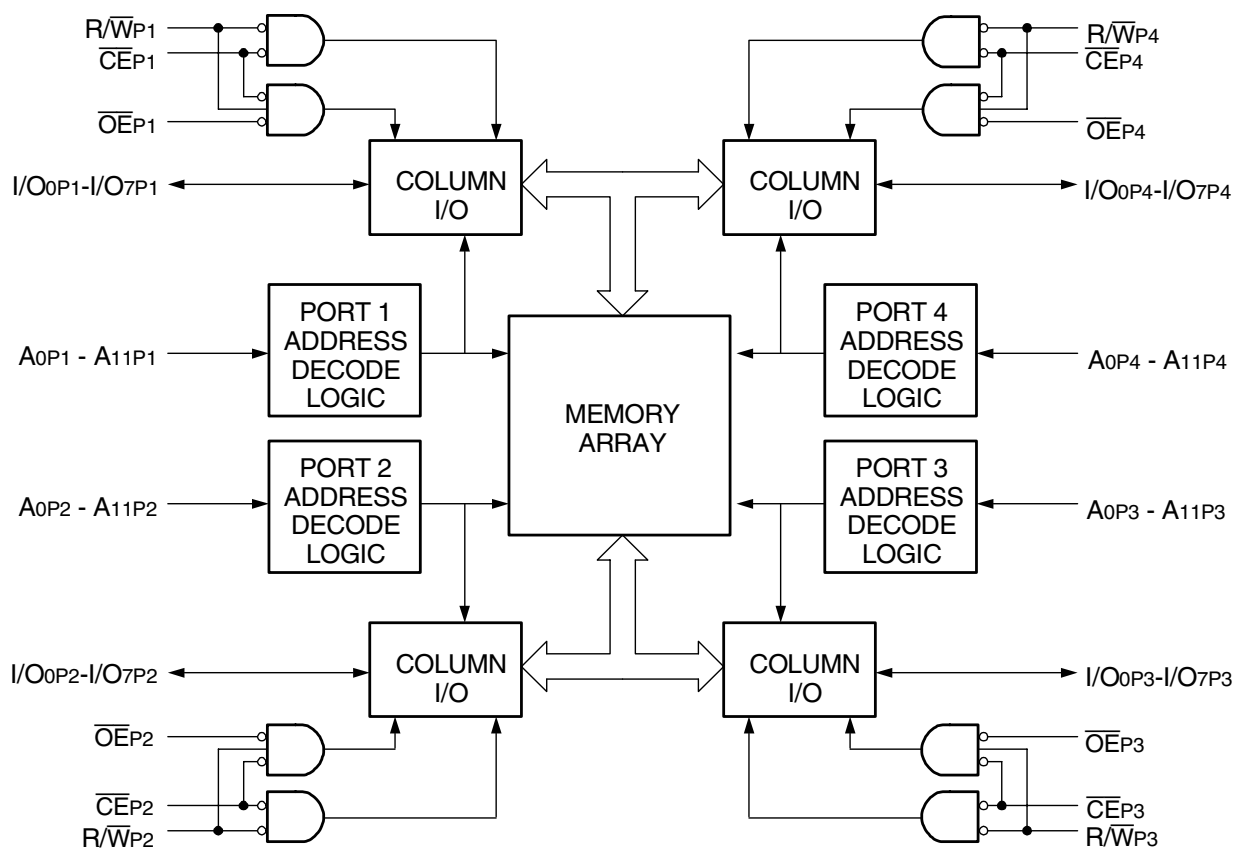
Description

The IDT7054 is a high-speed 4K x 8 FourPort™ Static RAM designed to be used in systems where multiple access into a common RAM is required. This FourPort Static RAM offers increased system performance in multiprocessor systems that have a need to communicate in real time and also offers added benefit for high-speed systems in which multiple access is required in the same cycle.

The IDT7054 is also designed to be used in systems where on-chip hardware port arbitration is not needed. This part lends itself to those systems which cannot tolerate wait states or are designed to be able to externally arbitrated or withstand contention when all ports simultaneously access the same FourPort RAM location.

The IDT7054 provides four independent ports with separate control,

Functional Block Diagram



3241 drw 01

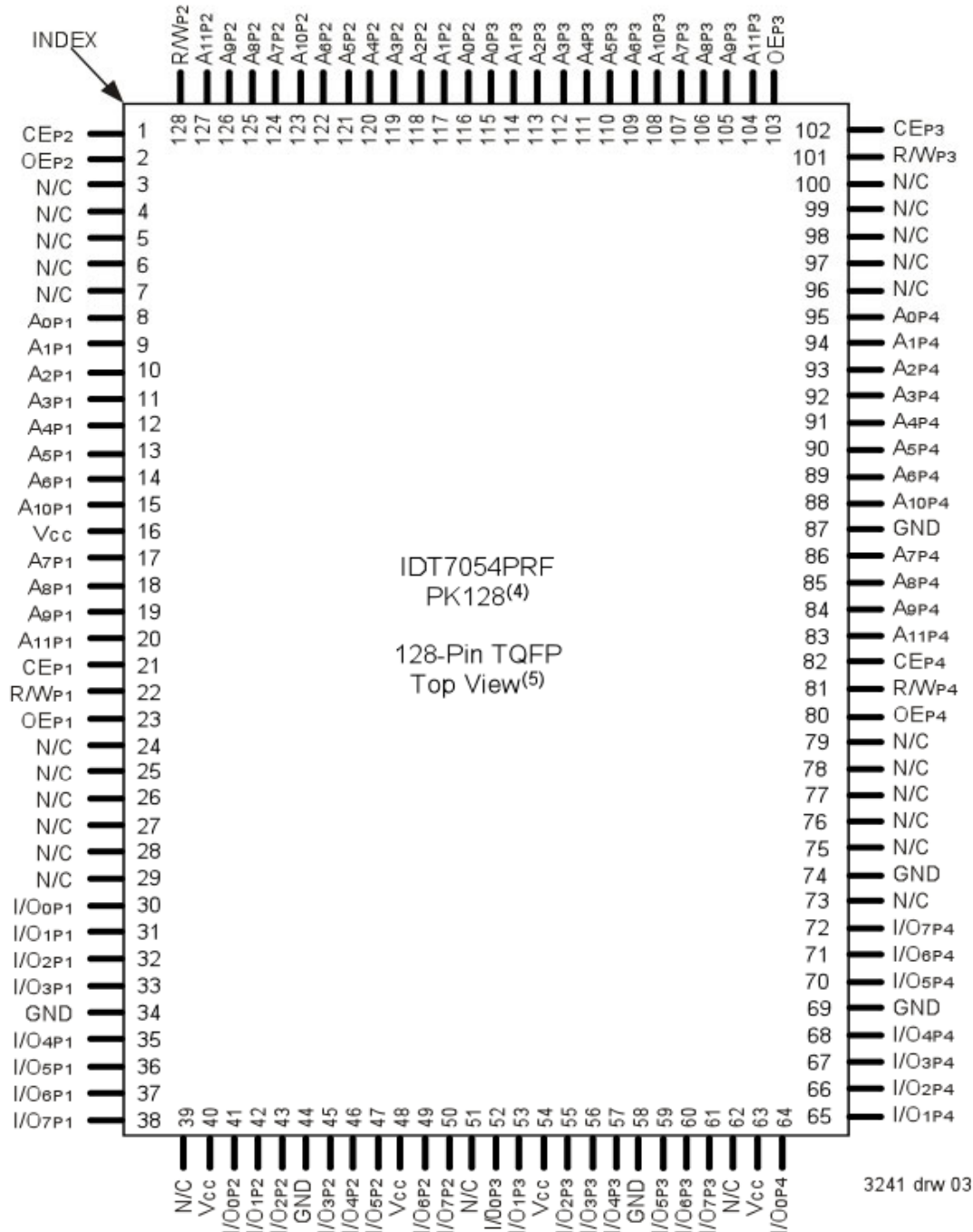
FEBRUARY 2015

address, and I/O pins that permit independent, asynchronous access for reads or writes to any location in memory. It is the user's responsibility to ensure data integrity when simultaneously accessing the same memory location from all ports. An automatic power down feature, controlled by $\overline{CE}$, permits the on-chip circuitry of each port to enter a very low power standby power mode.

Fabricated using CMOS high-performance technology, this FourPort SRAM typically operates on only 750mW of power.

The IDT7054 is packaged in a 128-pin Thin Quad Flatpack (TQFP).

Pin Configuration^(1,2,3)



NOTES:

1. All Vcc pins must be connected to the power supply.
2. All GND pins must be connected to the ground supply.
3. Package body is approximately 14mm x 20mm x 1.4mm.
4. This package code is used to reference the package diagram.
5. This text does not indicate orientation of the actual part-marking.

Pin Configurations^(1,2)

Symbol	Pin Name
A0 P1 - A11 P1	Address Lines - Port 1
A0 P2 - A11 P2	Address Lines - Port 2
A0 P3 - A11 P3	Address Lines - Port 3
A0 P4 - A11 P4	Address Lines - Port 4
I/O0 P1 - I/O7 P1	Data I/O - Port 1
I/O0 P2 - I/O7 P2	Data I/O - Port 2
I/O0 P3 - I/O7 P3	Data I/O - Port 3
I/O0 P4 - I/O7 P4	Data I/O - Port 4
$\overline{R/W}$ P1	Read/Write - Port 1
$\overline{R/W}$ P2	Read/Write - Port 2
$\overline{R/W}$ P3	Read/Write - Port 3
$\overline{R/W}$ P4	Read/Write - Port 4
GND	Ground
$\overline{CE}$ P1	Chip Enable - Port 1
$\overline{CE}$ P2	Chip Enable - Port 2
$\overline{CE}$ P3	Chip Enable - Port 3
$\overline{CE}$ P4	Chip Enable - Port 4
$\overline{OE}$ P1	Output Enable - Port 1
$\overline{OE}$ P2	Output Enable - Port 2
$\overline{OE}$ P3	Output Enable - Port 3
$\overline{OE}$ P4	Output Enable - Port 4
Vcc	Power

NOTES:

1. All Vcc pins must be connected to the power supply.
2. All GND pins must be connected to the ground supply.

3241 tbl 01

Recommended DC Operating Conditions

Symbol	Parameter	Min.	Typ.	Max.	Unit
Vcc	Supply Voltage	4.5	5.0	5.5	V
GND	Ground	0	0	0	V
V _{IH}	Input High Voltage	2.2	—	6.0 ⁽²⁾	V
V _{IL}	Input Low Voltage	-0.5 ⁽¹⁾	—	0.8	V

NOTES:

1. V_{IL} ≥ -1.5V for pulse width less than 10ns.
2. V_{TERM} must not exceed Vcc + 10%.

3241 tbl 02

Capacitance⁽¹⁾

(T_A = +25°C, f = 1.0MHz) TQFP ONLY

Symbol	Parameter	Conditions ⁽²⁾	Max.	Unit
C _{IN}	Input Capacitance	V _{IN} = 0V	9	pF
C _{OUT}	Output Capacitance	V _{OUT} = 0V	10	pF

3241 tbl 03

NOTES:

1. This parameter is determined by device characterization but is not production tested.
2. 3dV references the interpolated capacitance when the input and the output signals switch from 0V to 3V or from 3V to 0V.

Maximum Operating Temperature and Supply Voltage⁽¹⁾

Grade	Ambient Temperature	GND	Vcc
Commercial	0°C to +70°C	0V	5.0V ± 10%
Industrial	-40°C to +85°C	0V	5.0V ± 10%

3241 tbl 04

NOTES:

1. This is the parameter T_A. This is the "instant on" case temperature.

Absolute Maximum Ratings⁽¹⁾

Symbol	Rating	Commercial & Industrial	Unit
V _{TERM} ⁽²⁾	Terminal Voltage with Respect to GND	-0.5 to +7.0	V
T _{BIAS}	Temperature Under Bias	-55 to +125	°C
T _{STG}	Storage Temperature	-65 to +150	°C
I _{OUT}	DC Output Current	50	mA

3241 tbl 05

NOTES:

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
2. V_{TERM} must not exceed Vcc + 10% for more than 25% of the cycle time or 10ns maximum, and is limited to ≤ 20mA for the period of V_{TERM} ≥ Vcc + 10%.

DC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range^(1,5) (V_{CC} = 5.0V ± 10%)

Symbol	Parameter	Condition	Version	7054X20 Com'l Only		7054X25 Com'l & Ind		7054X35 Com'l Only		Unit	
				TYP. ⁽²⁾	Max.	TYP. ⁽²⁾	Max.	TYP. ⁽²⁾	Max.		
ICC1	Operating Power Supply Current (All Ports Active)	$\overline{CE} = V_{IL}$ Outputs Disabled $f = 0^{(3)}$	COM'L.	S L	150 150	300 250	150 150	300 250	150 150	300 250	mA
			IND.	S L	— —	— —	150 150	360 300	150 150	360 300	mA
ICC2	Dynamic Operating Current (All Ports Active)	$\overline{CE} = V_{IL}$ Outputs Disabled $f = f_{MAX}^{(4)}$	COM'L.	S L	240 210	370 325	225 195	350 305	210 180	335 290	mA
			IND.	S L	— —	— —	225 195	400 340	210 180	395 330	mA
ISB	Standby Current (All Ports - TTL Level Inputs)	$\overline{CE} = V_{IH}$ $f = f_{MAX}^{(4)}$	COM'L.	S L	70 60	95 80	60 50	85 70	40 35	75 60	mA
			IND.	S L	— —	— —	60 50	115 85	40 35	110 80	mA
ISB1	Full Standby Current (All Ports - All CMOS Level Inputs)	All Ports $\overline{CE} \geq V_{CC} - 0.2V$ $V_{IN} \geq V_{CC} - 0.2V$ or $V_{IN} \leq 0.2V$, $f = 0^{(3)}$	COM'L.	S L	1.5 0.3	15 1.5	1.5 0.3	15 1.5	1.5 0.3	15 1.5	mA
			IND.	S L	— —	— —	1.5 0.3	30 4.5	1.5 0.3	30 4.5	mA

3241 tbl 06

NOTES:

- 'X' in part number indicates power rating (S or L).
- V_{CC} = 5V, T_A = +25°C and are not production tested.
- f = 0 means no address or control lines change.
- At f = f_{MAX}, address and control lines (except Output Enable) are cycling at the maximum frequency read cycle of 1/t_{RC}, and using "AC Test Conditions" of input levels of GND to 3V.
- For the case of one port, divide the appropriate current above by four.

DC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range (V_{CC} = 5.0V ± 10%)

Symbol	Parameter	Test Conditions	7054S		7054L		Unit
			Min.	Max.	Min.	Max.	
I _{LI}	Input Leakage Current ⁽¹⁾	V _{CC} = 5.5V, V _{IN} = 0V to V _{CC}	—	10	—	5	μA
I _{LO}	Output Leakage Current	$\overline{CE} = V_{IH}$, V _{OUT} = 0V to V _{CC}	—	10	—	5	μA
V _{OL}	Output Low Voltage	I _{OL} = 4mA	—	0.4	—	0.4	V
V _{OH}	Output High Voltage	I _{OH} = -4mA	2.4	—	2.4	—	V

NOTE:

- At V_{CC} ≤ 2.0V input leakages are undefined.

2674 tbl 07

AC Test Conditions

Input Pulse Levels	GND to 3.0V
Input Rise/Fall Times	3ns Max.
Input Timing Reference Levels	1.5V
Output Reference Levels	1.5V
Output Load	Figures 1 and 2

3241 tbl 08

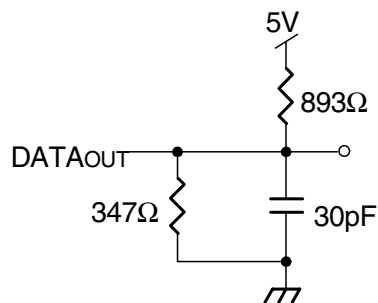
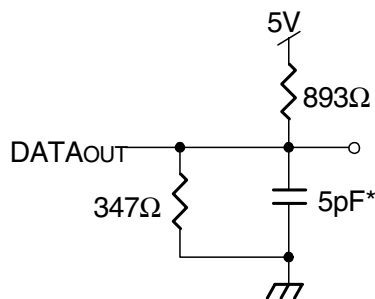


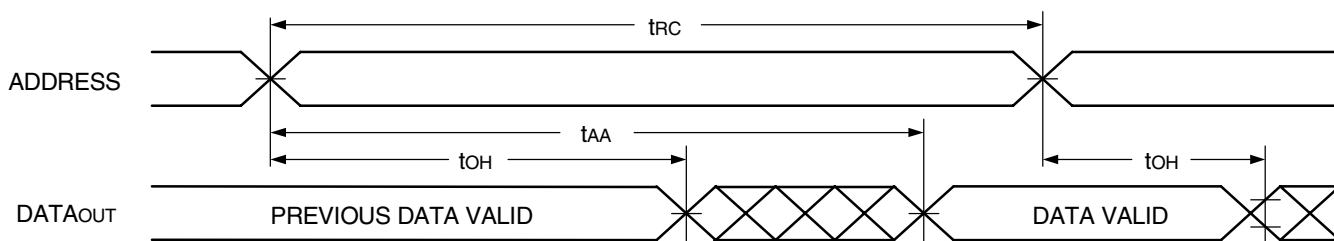
Figure 1. AC Output Test Load



3241 drw 04

Figure 2. Output Test Load
(for tLZ, tHZ, twZ, tow)
*Including scope and jig

Timing Waveform of Read Cycle No. 1, Any Port⁽¹⁾



3241 drw 05

NOTE:

1. $\overline{R/\overline{W}} = V_{IH}$, $\overline{OE} = V_{IL}$, and $\overline{CE} = V_{IL}$.

AC Electrical Characteristics Over the Operating Temperature and Supply Voltage⁽³⁾

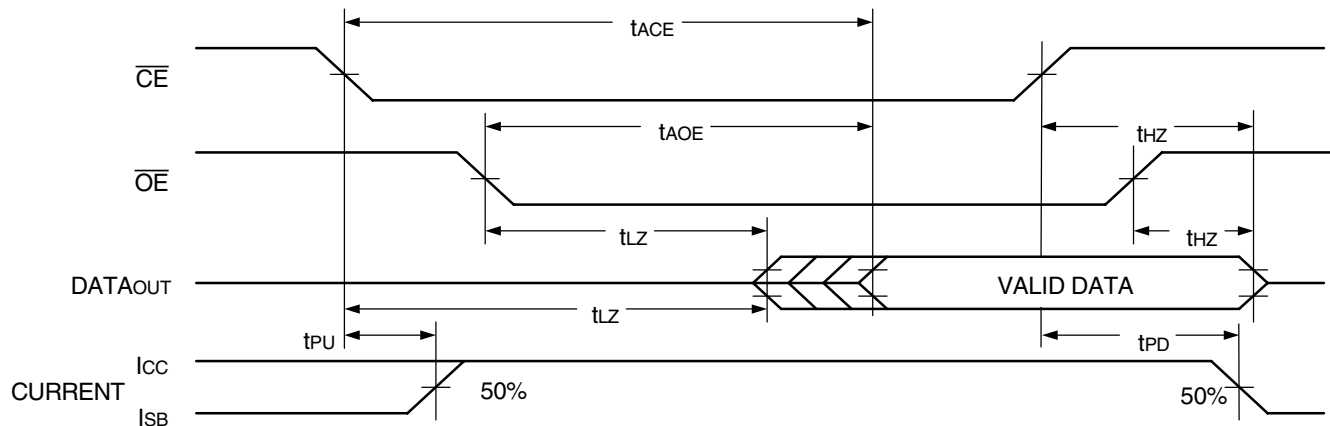
Symbol	Parameter	7054X20 Com'l Only		7054X25 Com'l & Ind		7054X35 Com'l Only		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
READ CYCLE								
tRC	Read Cycle Time	20	—	25	—	35	—	ns
tAA	Address Access Time	—	20	—	25	—	35	ns
tACE	Chip Enable Access Time	—	20	—	25	—	35	ns
tAOE	Output Enable Access Time	—	10	—	15	—	25	ns
tOH	Output Hold from Address Change	0	—	0	—	0	—	ns
tLZ	Output Low-Z Time ^(1,2)	5	—	5	—	5	—	ns
tHZ	Output High-Z Time ^(1,2)	—	12	—	15	—	15	ns
tPU	Chip Enable to Power Up Time ⁽²⁾	0	—	0	—	0	—	ns
tPD	Chip Disable to Power Down Time ⁽²⁾	—	20	—	25	—	35	ns

3241 tbl 09

NOTES:

1. Transition is measured 0mV from Low or High-impedance voltage with the Output Test Load (Figure 2).
2. This parameter is guaranteed by device characterization but is not production tested.
3. 'X' in part number indicates power rating (S or L).

Timing Waveform of Read Cycle No. 2, Any Port^(1, 2)



3241 drw 06

NOTES:

1. $R/\overline{W} = V_{IH}$ for Read Cycles.
2. Addresses valid prior to or coincident with $\overline{CE}$ transition LOW.

AC Electrical Characteristics Over the Operating Temperature and Supply Voltage⁽⁵⁾

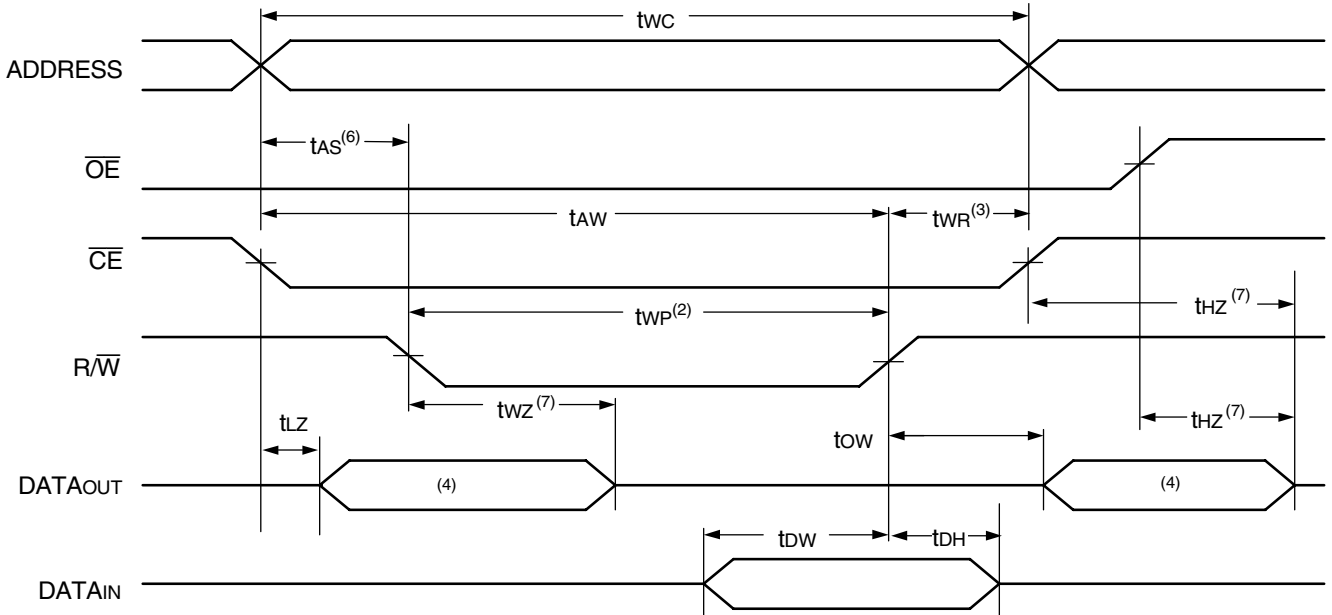
Symbol	Parameter	7054X20 Com'l Only		7054X25 Com'l & Ind		7054X35 Com'l Only		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
WRITE CYCLE								
tWC	Write Cycle Time	20	—	25	—	35	—	ns
tEW	Chip Enable to End-of-Write	15	—	20	—	30	—	ns
tAW	Address Valid to End-of-Write	15	—	20	—	30	—	ns
tAS	Address Set-up Time	0	—	0	—	0	—	ns
tWP	Write Pulse Width ⁽³⁾	15	—	20	—	30	—	ns
tWR	Write Recovery Time	0	—	0	—	0	—	ns
tDW	Data Valid to End-of-Write	15	—	15		20	—	ns
tHZ	Output High-Z Time ^(1,2)	—	15	—	15	—	15	ns
tDH	Data Hold Time	0	—	0	—	0	—	ns
tWZ	Write Enable to Output in High-Z ^(1,2)	—	12	—	15	—	15	ns
tOW	Output Active from End-of-Write ^(1,2)	0	—	0	—	0	—	ns
tWDD	Write Pulse to Data Delay ⁽⁴⁾	—	35	—	45	—	55	ns
tDDD	Write Data Valid to Read Data Delay ⁽⁴⁾	—	30	—	35	—	45	ns

3241 tbl 10

NOTES:

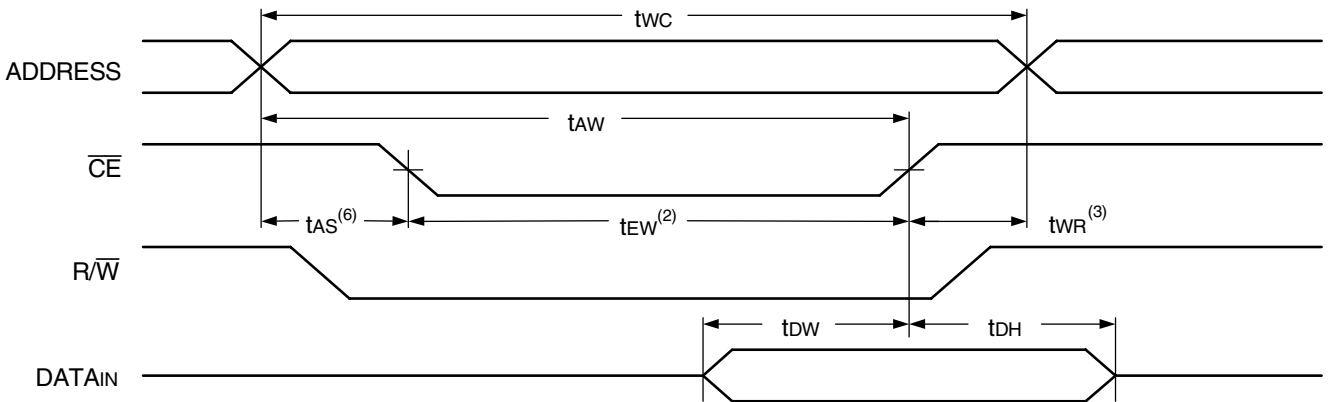
1. Transition is measured 0mV from Low or High-impedance voltage with the Output Test Load (Figure 2).
2. This parameter is guaranteed by device characterization but is not production tested.
3. If $\overline{OE} = V_{IL}$ during a $R\overline{W}$ controlled write cycle, the write pulse width must be the larger of t_{WP} or (t_{WZ} + t_{OW}) to allow the I/O drivers to turn off data to be placed on the bus for the required t_{DW}. If $\overline{OE} = V_{IH}$ during an $R\overline{W}$ controlled write cycle, this requirement does not apply and the write pulse can be as short as the specified t_{WP}. Specified for $\overline{OE} = V_{IH}$ (refer to "Timing Waveform of Write Cycle", Note 8).
4. Port-to-port delay through RAM cells from writing port to reading port, refer to "Timing Waveform of Write with Port-to-Port Read".
5. 'X' in part number indicates power rating.

Timing Waveform of Write Cycle No. 1, R/W Controlled Timing^(5,8)



3241 drw 07

Timing Waveform of Write Cycle No. 2, CE Controlled Timing^(1,5)

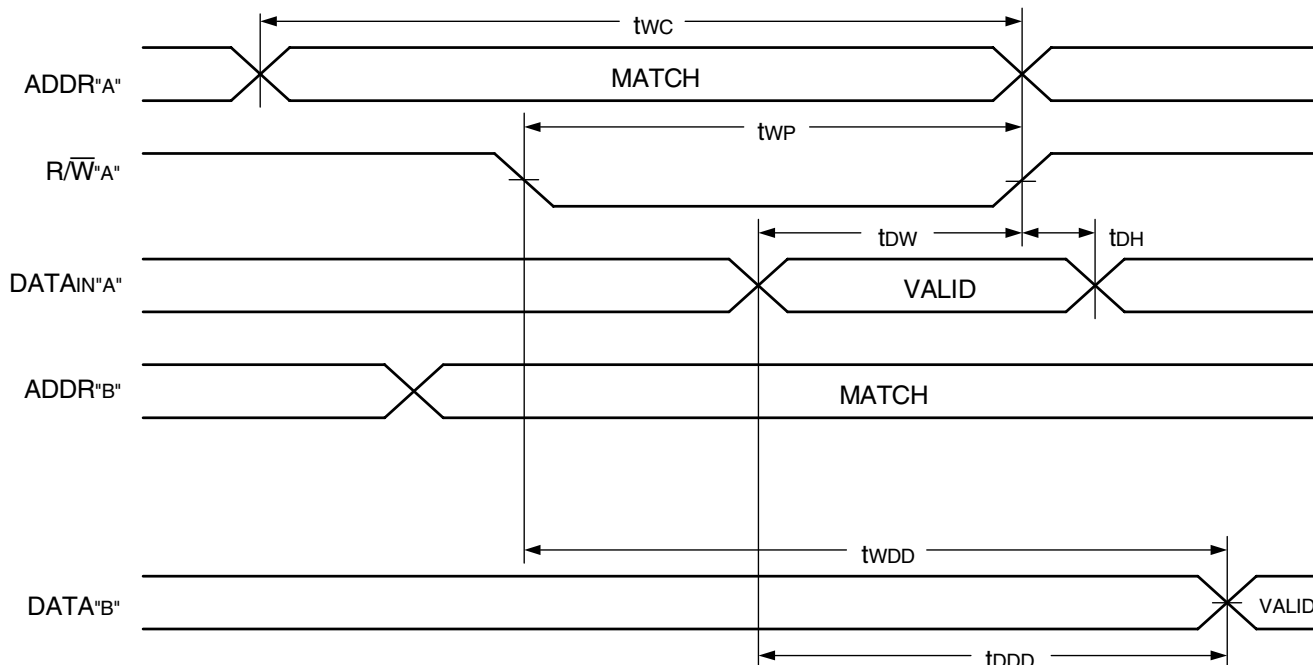


3241 drw 08

NOTES:

1. $\overline{R/\overline{W}}$ or $\overline{CE} = V_{IH}$ during all address transitions.
2. A write occurs during the overlap (t_{EW} or t_{WP}) of a $\overline{CE} = V_{IL}$ and a $\overline{R/\overline{W}} = V_{IL}$.
3. t_{WR} is measured from the earlier of $\overline{CE}$ or $\overline{R/\overline{W}} = V_{IH}$ to the end of write cycle.
4. During this period, the I/O pins are in the output state, and input signals must not be applied.
5. If the $\overline{CE}$ LOW transition occurs simultaneously with or after the $\overline{R/\overline{W}} = V_{IL}$ transition, the outputs remain in the High-impedance state.
6. Timing depends on which enable signal is asserted last, $\overline{CE}$ or $\overline{R/\overline{W}}$.
7. Transition is measured 0mV from Low or High-impedance voltage with the Output Test Load (Figure 2). This parameter is guaranteed but is not production tested.
8. If $\overline{OE} = V_{IL}$ during a $\overline{R/\overline{W}}$ controlled write cycle, the write pulse width must be the larger of t_{WP} or ($t_{WZ} + t_{DW}$) to allow the I/O drivers to turn off data to be placed on the bus for the required t_{OW} . If $\overline{OE} = V_{IH}$ during an $\overline{R/\overline{W}}$ controlled write cycle, this requirement does not apply and the write pulse can be as short as the specified t_{WP} .

Timing Waveform of Write with Port-to-Port Read^(1, 2)



NOTES:

1. $\overline{OE} = V_{IL}$ for the reading ports.
2. All timing is the same for left and right ports. Port "A" may be either of the four ports and Port "B" is any other port.

3241 drw 09

Functional Description

The IDT7054 provides four ports with separate control, address, and I/O pins that permit independent access for reads or writes to any location in memory. These devices have an automatic power down feature controlled by $\overline{CE}$. The $\overline{CE}$ controls on-chip power down circuitry that permits the respective port to go into standby mode when not selected ($\overline{CE} = V_{IH}$). When a port is enabled, access to the entire memory array is permitted. Each port has its own Output Enable control ($\overline{OE}$). In the read mode, the port's $\overline{OE}$ turns on the output drivers when set LOW. READ/ WRITE conditions are illustrated in the table.

Table I – Read/Write Control

Any Port ⁽¹⁾				
R/W	$\overline{CE}$	$\overline{OE}$	D0-7	Function
X	H	X	Z	Port Deselected: Power-Down
X	H	X	Z	$\overline{CEP1}=\overline{CEP2}=\overline{CEP3}=\overline{CEP4}=V_{IH}$ Power Down Mode ISB or ISB1
L	L	X	DATAin	Data on port written into memory ⁽²⁾
H	L	L	DATAout	Data in memory output on port
X	X	H	Z	Outputs Disabled

3241 tbl 11

NOTES:

1. "H" = V_{IH} , "L" = V_{IL} , "X" = Don't Care, "Z" = High Impedance
2. For valid write operation, no more than one port can write to the same address location at the same time.

Ordering Information

XXXX	A	999	A	A	A	A	
Device Type	Power	Speed	Package		Process/ Temperature Range		
						Blank 8	Tube or Tray Tape and Reel
						Blank I ⁽¹⁾	Commercial (0°C to +70°C) Industrial (-40°C to +85°C)
						G ⁽²⁾	Green
						PRF	128-Pin Thin Quad Plastic Flatpack (PK128)
						20 25 35	Commercial Only Commercial & Industrial Commercial Only
						L S	Low Power Standard Power
						7054	32K (4K x 8) FourPort RAM

3241 drw 10

NOTE:

1. Industrial temperature range is available. For other speeds, packages and powers contact your sales office.
2. Green parts available. For specific speeds, packages and powers contact your local sales office.

Datasheet Document History

1/18/99:	Initiated datasheet document history Converted to new format Cosmetic typographical corrections Added additional notes to pin configurations
6/4/99:	Changed drawing format Page 1 Corrected DSC number
9/1/99:	Removed Preliminary
11/10/99:	Replaced IDT logo
5/23/00:	Page 4 Increased storage temperature parameter Clarified TA parameter Page 5 DC Electrical parameters—changed wording from "open" to "disabled" Changed ±200mV to 0mV in notes
10/22/01:	Page 2 & 3 Added date revision for pin configurations Page 5, 7 & 8 Added Industrial temp to column heading for 25ns speed to DC & AC Electrical Characteristics Page 11 Added Industrial temp offering to 25ns ordering information Page 4, 5, 7 & 8 Removed Industrial temp footnote from all tables Page 6 Changed 5ns to 3ns in AC Test Conditions table Page 1 & 11 Replace ™ logo with ® logo

Datasheet Document History (con't)

02/20/15: Page 1 Added green availability to features
 Page 2 Removed IDT in reference to fabrication
 Page 2 2V battery backup for Low-power versions are no longer offered
 Page 2,3 & 10 The package code PK128-1 changed to PK128 to match standard package codes
 Page 10 Added Tape and Reel and Green to Ordering Information
 Pages 1-10 Removed all military data including the G108 pin configuration, changed table headings and ordering information
 to indicate that there is no longer a military offering for this 7054 device



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